Ordering number : EN2510B

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SC4134 — NPN Epitaxial Planar Silicon Transistor
High-Voltage Switching Applications

Applications

- Power supplies, relay drivers, lamp drivers

Features

- Adoption FBET, MBIT processes
- Fast switching speed
- Small and slim package permitting 2SC4134-applied sets to be made more compact
- High breakdown voltage and large current capacity

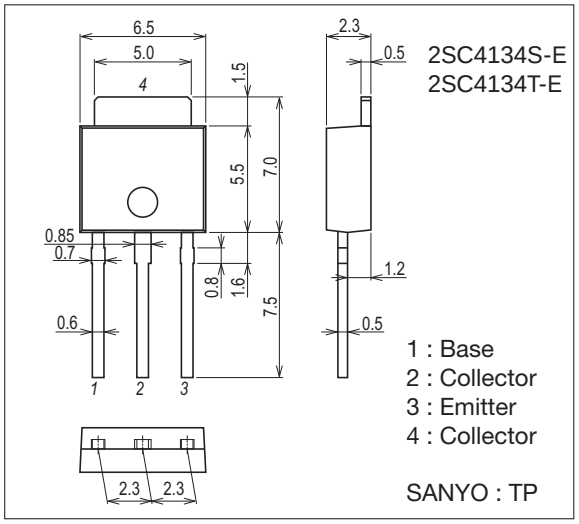
Specifications

Absolute Maximum Ratings at Ta=25°C

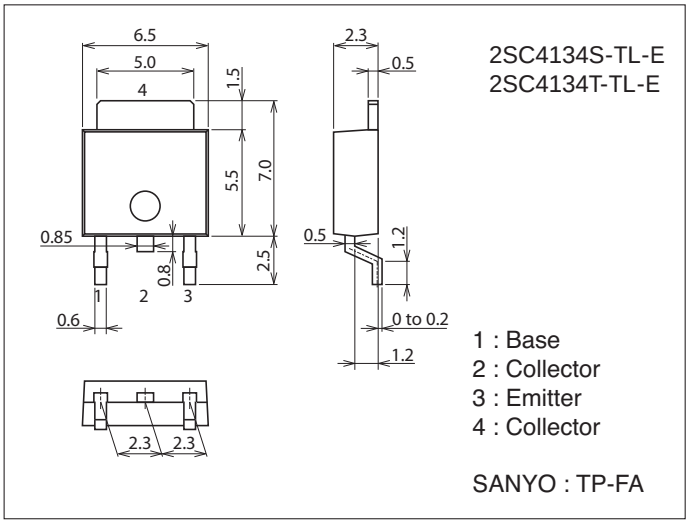
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		120	V
Collector-to-Emitter Voltage	V_{CEO}		100	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		1	A
Collector Current (Pulse)	I_{CP}		2	A

Continued on next page.

Package Dimensions unit : mm (typ)
7518-003



Package Dimensions unit : mm (typ)
7003-003

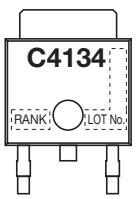


Product & Package Information

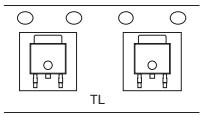
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

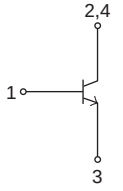
Marking (TP, TP-FA)



Packing Type (TP-FA) : TL



Electrical Connection



Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	P_C		0.8	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		−55 to +150	°C

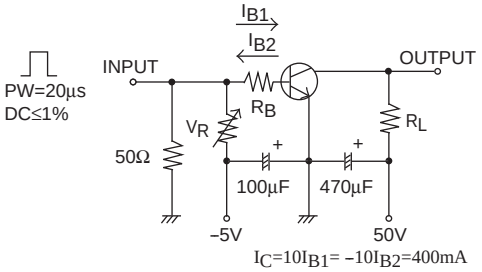
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=100V, I_E=0A			100	nA
Emitter Cutoff Current	I_{EBO}	V_{EB}=4V, I_C=0A			100	nA
DC Current Gain	h_{FE}	V_{CE}=5V, I_C=100mA	100*		400*	
Gain-Bandwidth Product	f_T	V_{CE}=10V, I_C=100mA		120		MHz
Output Capacitance	Cob	V_{CB}=10V, f=1MHz		8.5		pF
Collector-to-Emitter Saturation Voltage	V_{CE}(sat)	I_C=400mA, I_B=40mA		0.1	0.4	V
Base-to-Emitter Saturation Voltage	V_{BE}(sat)	I_C=400mA, I_B=40mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=10μA, I_E=0A	120			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA, R_{BE}=∞	100			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0A	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		80		ns
Storage Time	t_{stg}			850		ns
Fall Time	t_f			50		ns

* : The 2SC4134 is classified by 100mA h_{FE} as follows :

Rank	R	S	T
h_{FE}	100 to 200	140 to 280	200 to 400

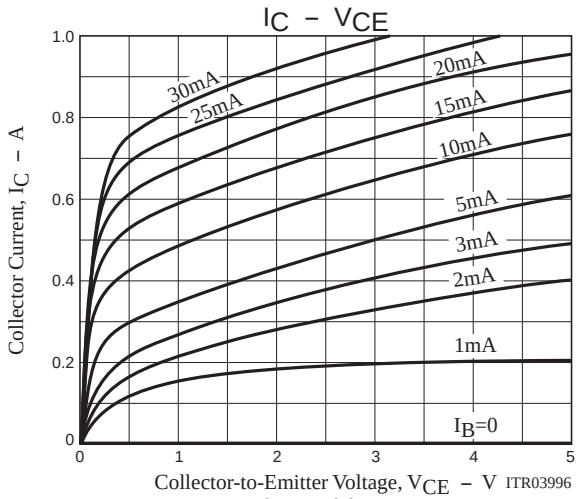
Switching Time Test Circuit

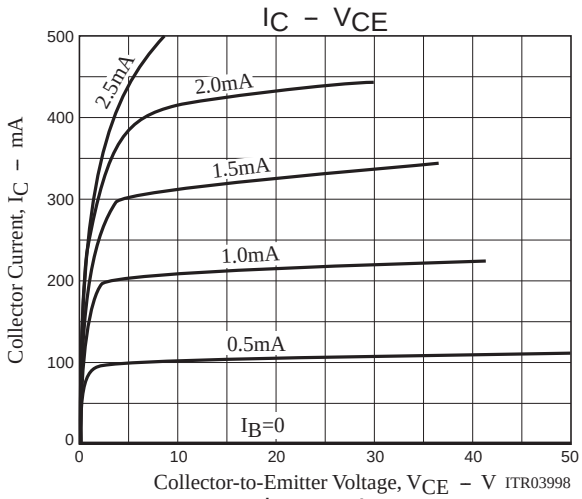


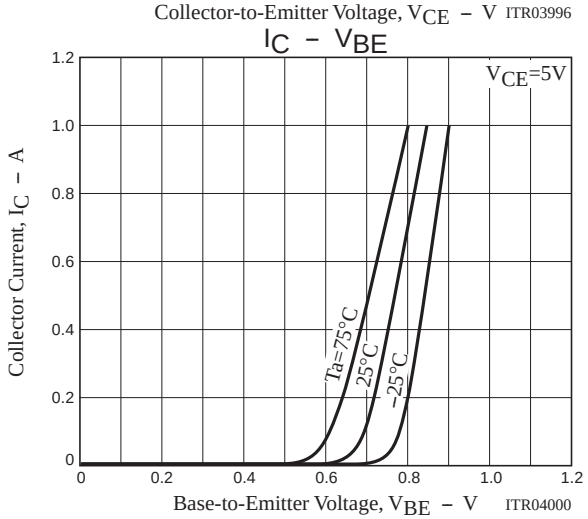
I_C=10I_{B1}= −10I_{B2}=400mA

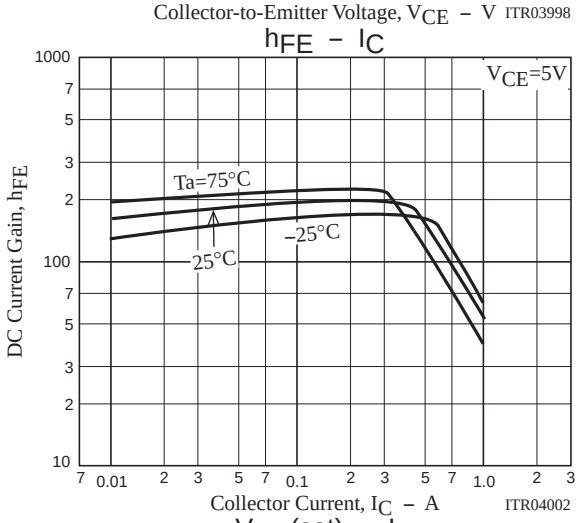
Ordering Information

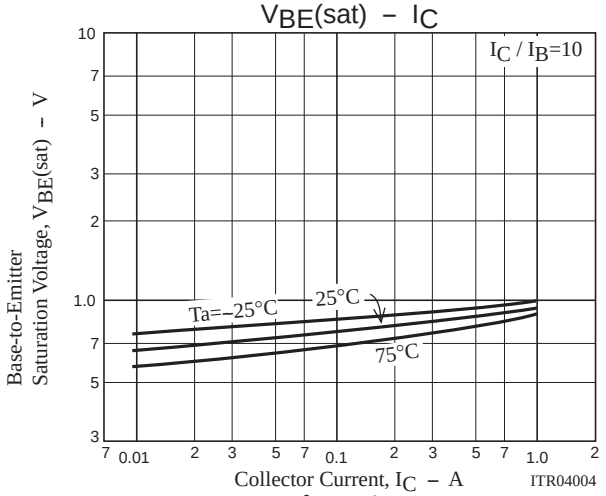
Device	Package	Shipping	memo
2SC4134S-E	TP	500pcs./bag	Pb Free
2SC4134T-E	TP	500pcs./bag	
2SC4134S-TL-E	TP-FA	700pcs./reel	
2SC4134T-TL-E	TP-FA	700pcs./reel	

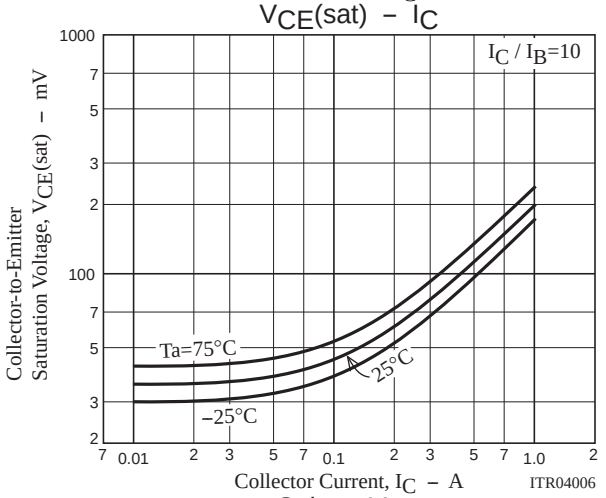

IC – VCE
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
ITR03996
30mA
25mA
20mA
15mA
10mA
5mA
3mA
2mA
1mA
IB=0

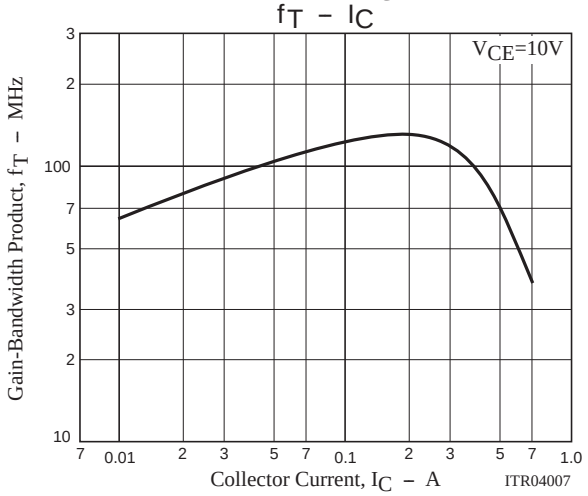

IC – VCE
Collector Current, IC – mA
Collector-to-Emitter Voltage, VCE – V
ITR03998
2.5mA
2.0mA
1.5mA
1.0mA
0.5mA
IB=0

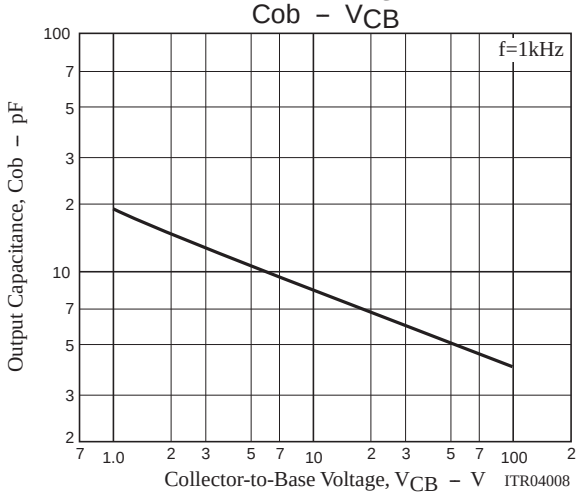

IC – VBE
VCE=5V
Collector Current, IC – A
Base-to-Emitter Voltage, VBE – V
ITR04000
Ta=75°C
25°C
–25°C

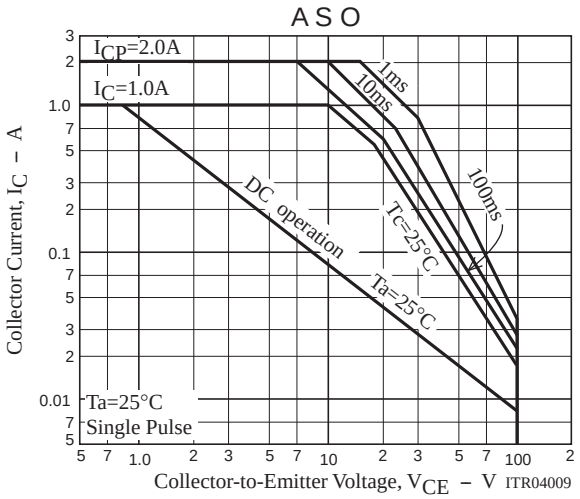

hFE – IC
VCE=5V
DC Current Gain, hFE
Collector Current, IC – A
ITR04002
Ta=75°C
25°C
–25°C

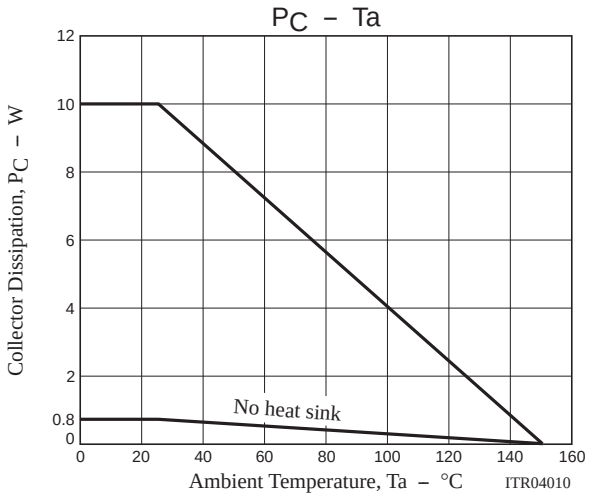

VBE(sat) – IC
IC / IB=10
Base-to-Emitter Saturation Voltage, VBE(sat) – V
Collector Current, IC – A
ITR04004
Ta=–25°C
25°C
75°C


VCE(sat) – IC
IC / IB=10
Collector-to-Emitter Saturation Voltage, VCE(sat) – mV
Collector Current, IC – A
ITR04006
Ta=75°C
25°C
–25°C


fT – IC
VCE=10V
Gain-Bandwidth Product, fT – MHz
Collector Current, IC – A
ITR04007


Cob – VCB
f=1kHz
Output Capacitance, Cob – pF
Collector-to-Base Voltage, VCB – V
ITR04008


A S O
I_{CP}=2.0A
I_C=1.0A
1ms
10ms
100ms
DC operation
Tc=25°C
Ta=25°C
Ta=25°C
Single Pulse
Collector Current, I_C – A
Collector-to-Emitter Voltage, V_{CE} – V
ITR04009


P_C – Ta
No heat sink
Collector Dissipation, P_C – W
Ambient Temperature, Ta – °C
ITR04010

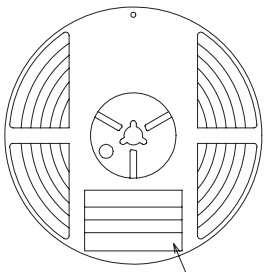
Taping Specification

2SC4134S-TL-E, 2SC4134T-TL-E

Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

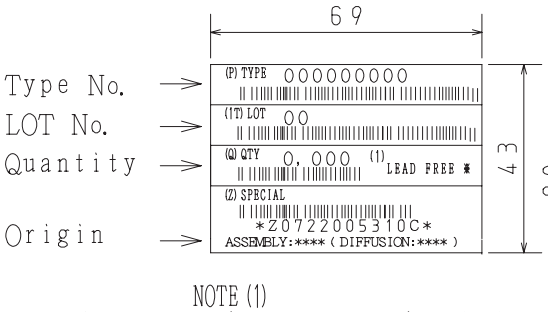
Packing method



Reel label

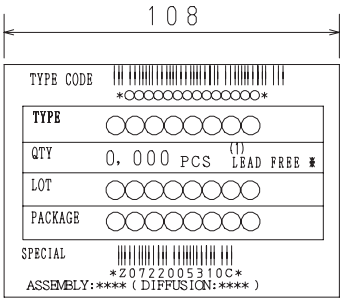
Reel label, Inner box label

(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.

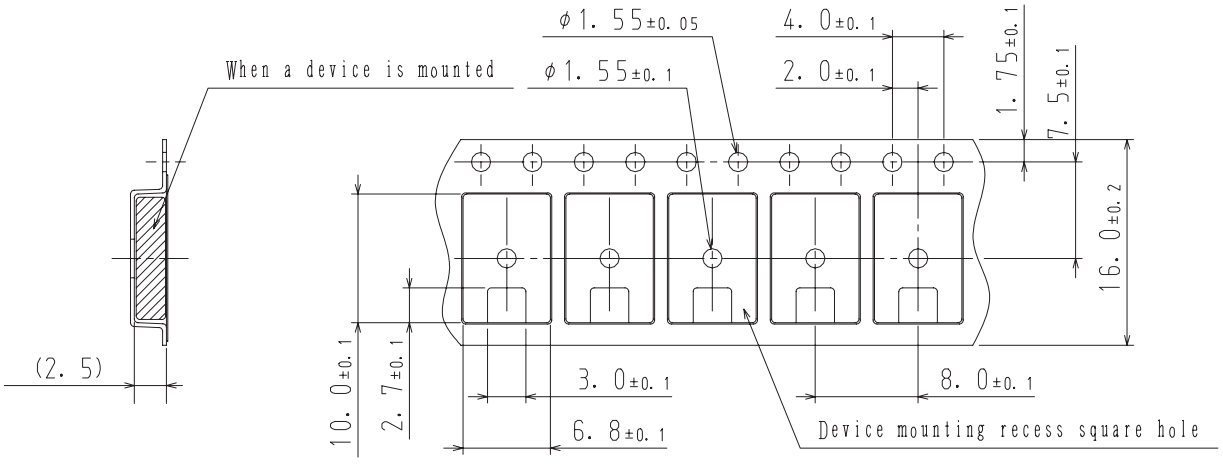


NOTE (1)
The LEAD FREE ※ description shows that the surface treatment of the terminal is lead free.

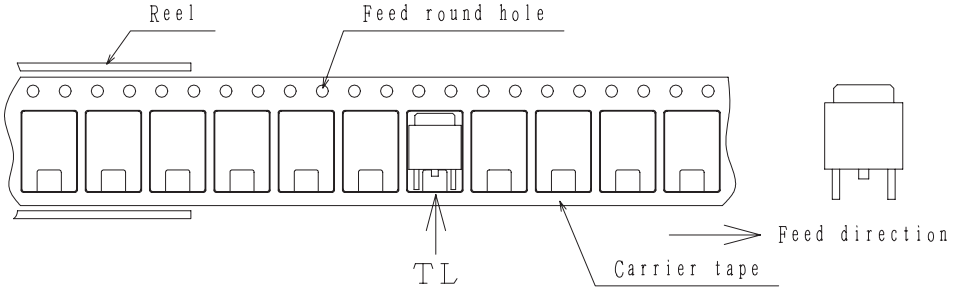
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



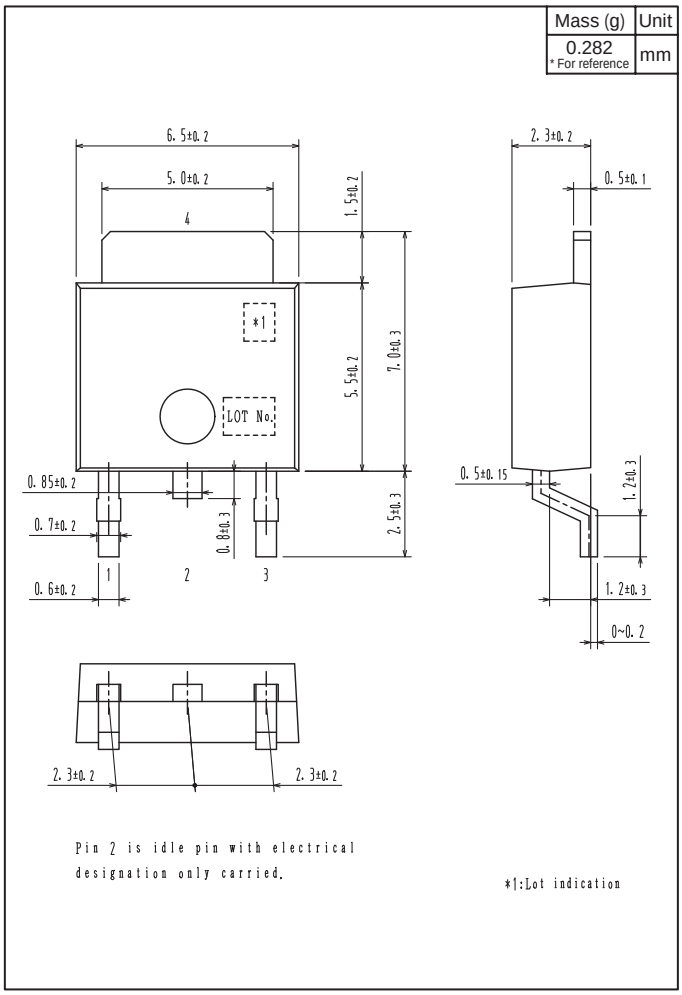
2. Device placement direction



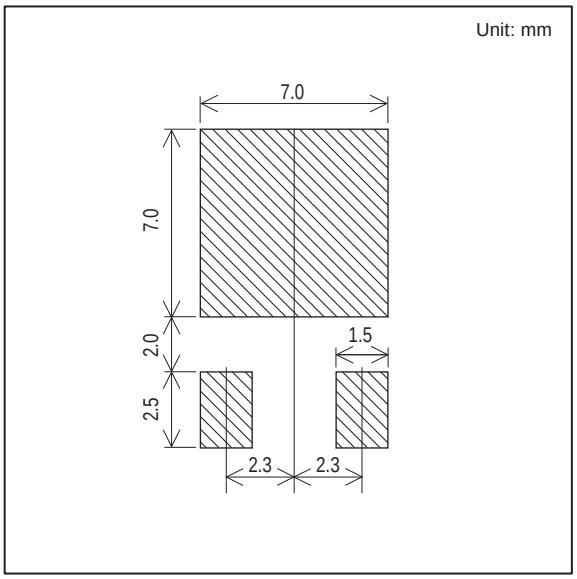
Those with one electrode terminal on the feed hole side·····TL

Outline Drawing

2SC4134S-TL-E, 2SC4134T-TL-E



Land Pattern Example



Bag Packing Specification

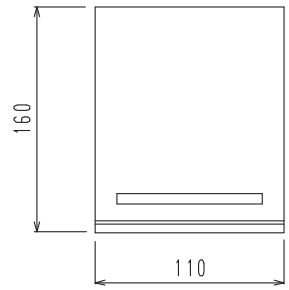
2SC4134S-E, 2SC4134T-E

1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP		B-1	A-1	A-2
	500	10,000	50,000	30,000
	Packing format (Dimensions: mm (external))			
	Inner box		Outer box	
	B-1		A-1	A-2
	445×225×55		470×250×300	470×250×190

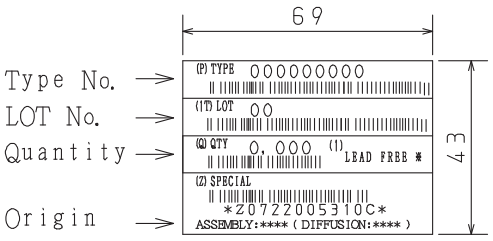
2. Bag dimensions

(unit: mm)



3. Bag label, Inner box label

(unit: mm)



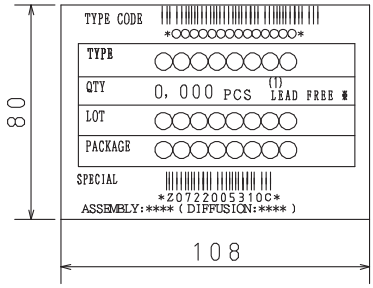
NOTE (1)
The LEAD FREE ※ description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

4. Outer box label

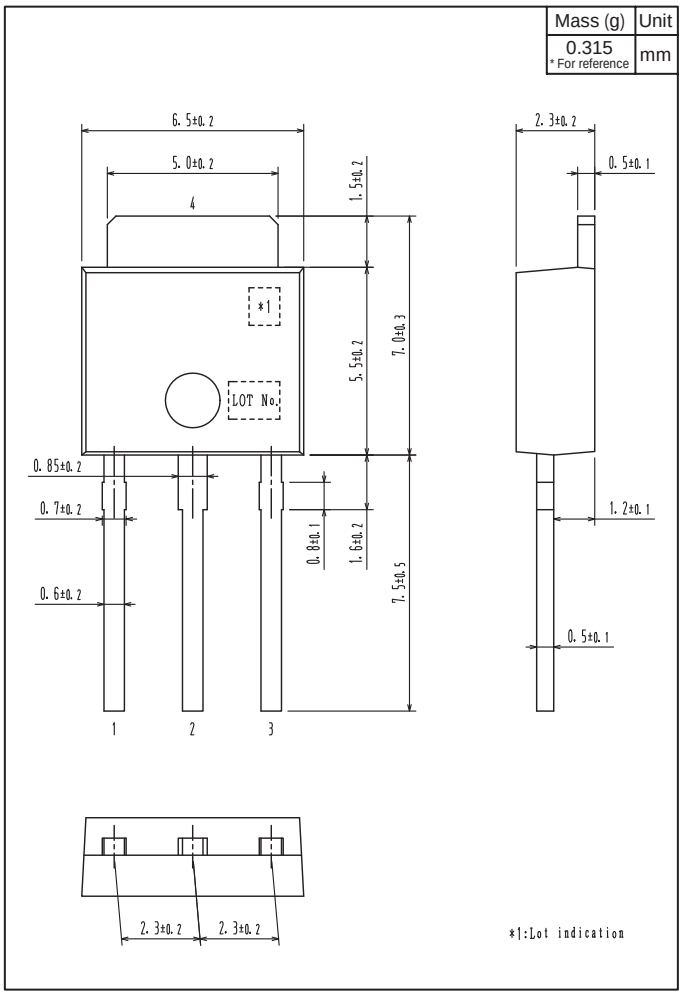
(unit: mm)

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



Outline Drawing

2SC4134S-E, 2SC4134T-E



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